

R6024ENJ

Nch 600V 24A Power MOSFET

V _{DSS}	600V
R _{DS(on)} (Max.)	0.165Ω
I _D	±24A
PD	245W

Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (V_{GSS}) guaranteed to be ±20V.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

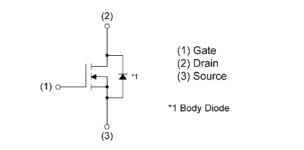
Application

Switching

6) Pb-free lead plating ; RoHS compliant

• Outline TO-263 (2) SC-83 LPT(S) (3)

●Inner circuit



Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	24
•	Basic ordering unit (pcs)	1000
	Taping code	TL
	Marking	R6024ENJ

• Absolute maximum ratings (T_a = 25°C ,unless otherwise specified)

Parameter		Symbol	Value	Unit
Drain - Source voltage		V _{DSS}	600	V
Continuous dusin suurant	۱ _D *1	±24	А	
Continuous drain current $T_{C} = 100^{\circ}C$		۱ _D *1	±13.0	А
Pulsed drain current		۱ _{DP} *2	±72	А
Cata Sauraa valtaga	static	V _{GSS}	±20	V
Gate - Source voltage	AC(f>1Hz)		±30	V
Avalanche current, repetitive		I _{AR}	4.1	А
Avalanche energy, single pulse		E_{AS}^{*3}	497	mJ
Avalanche energy, repetitive		E_{AR}^{*3}	0.75	mJ
Power dissipation ($T_C = 25^{\circ}C$)		P _D *4	245	W
Junction temperature		Tj	150	°C
Operating junction and storage ter	mperature range	T _{stg}	-55~+150	C°

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Conditions	Values	Unit
Reverse diode dv/dt	dv/dt	-	15	V/ns
Drain - Source voltage slope	dv/dt	V _{DS} = 480V, T _j = 25°C	50	V/ns

•Thermal resistance

Baramatar	Sumbol		Values		Unit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC}	-	-	0.51	°C/W
Thermal resistance, junction - ambient	R _{thJA} *5	-	-	80	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	-	265	°C

•Electrical characteristics (T_a = 25°C)

Parameter	Sumbol	Conditions		Values		Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 1mA	600	-	-	V
		V _{DS} = 600V, V _{GS} = 0V				
Zero gate voltage drain current	I _{DSS}	T _j = 25°C	-	0.1	100	μA
		T _j = 125°C	-	-	1000	
Gate - Source leakage current	I _{GSS}	V_{GS} = ±20V, V_{DS} = 0V	-	-	±100	nA
Gate threshold voltage	$V_{GS(th)}$	V _{DS} = 10V, I _D = 1mA	2	-	4	V
		V _{GS} = 10V, I _D = 11.3A				
Static drain - source on - state resistance	${\sf R}_{\sf DS(on)}^{*6}$	T _j = 25°C	-	0.150	0.165	Ω
		T _j = 125°C	-	0.320	-	
Gate resistance	R _G	f =1MHz, open drain	-	6.1	-	Ω



• Electrical characteristics (T_a = 25°C)

Deremeter	Cump of	Conditions		Values		l loit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Transfer Admittance	Y _{fs} ⁵6	V _{DS} = 10V, I _D = 12A	6.5	13.0	-	S
Input capacitance	C _{iss}	V _{GS} = 0V	-	1650	-	
Output capacitance	C _{oss}	V _{DS} = 25V	-	1350	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	160	-	
Effective output capacitance, energy related	C _{o(er)}	V _{GS} = 0V	-	66	-	
Effective output capacitance, time related	C _{o(tr)}	V _{DS} = 0V to 480V	-	314	-	рF
Turn - on delay time	t _{d(on)} *6	$V_{DD} \simeq 300 \text{V}, \text{V}_{GS} = 10 \text{V}$	-	35	-	
Rise time	t _r *6	I _D = 12A	-	50	-	
Turn - off delay time	t _{d(off)} *6	R _L ≃ 27.4Ω	_	180	-	ns
Fall time	t _f *6	R _G = 10Ω	-	50	-	

• Gate charge characteristics ($T_a = 25^{\circ}C$)

Deremeter	Sumbol	Conditions		Values		Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	Q_g^{*6}	V _{DD} ≃ 300V,	-	70	-	
Gate - Source charge	Q _{gs} *6	I _D = 24A,	-	10	-	nC
Gate - Drain charge	Q _{gd} *6	V _{GS} = 10V	-	35	-	
Gate plateau voltage	V _(plateau)	V _{DD} = 300V, I _D = 24A	-	6.4	-	V

*1 Limited only by maximum channel temperature allowed.

*2 Pw \leq 10µs, Duty cycle \leq 1%

*3 L \doteqdot 70mH, V_{DD}=50V, R_G=25 Ω , STARTING T_i=25°C

*4 T_C=25°C

*5 Mounted on a epoxy PCB FR4 (25mm x 27mm x 0.8mm)

*6 Pulsed



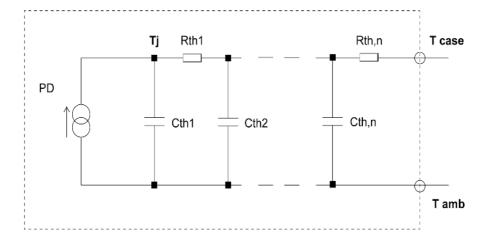


•Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Symbol	Conditions		Values		Unit
	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous forward current	ا _S *1	T _c = 25°C	-	-	24	A
Pulse forward current	۱ _{SP} *2	$T_{c} = 25 C$	-	-	72	А
Forward voltage	V _{SD} *6	V _{GS} = 0V, I _S = 24A	-	-	1.5	V
Reverse recovery time	t _{rr} *6		-	625	-	ns
Reverse recovery charge	Q _{rr} *6	I _S = 24A, V _{GS} =0V di/dt = 100A/µs	-	13.3	-	μC
Peak reverse recovery current	I _{mm} *6		-	42	-	А

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	0.0578		C _{th1}	0.00248	
R _{th2}	0.218	K/W	C _{th2}	0.00916	Ws/K
R _{th3}	0.604		C _{th3}	0.209	





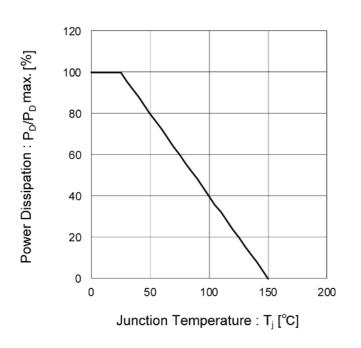
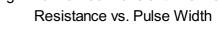


Fig.1 Power Dissipation Derating Curve Fig.2 Normalized Transient Thermal



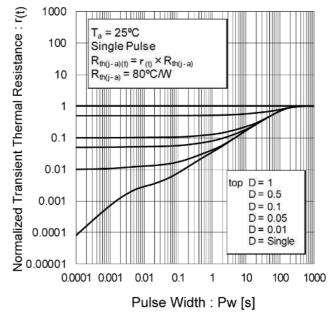
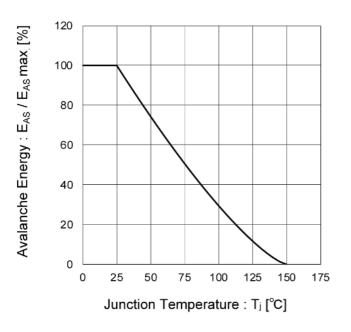


Fig.3 Avalanche Energy Derating Curve vs. Junction Temperature





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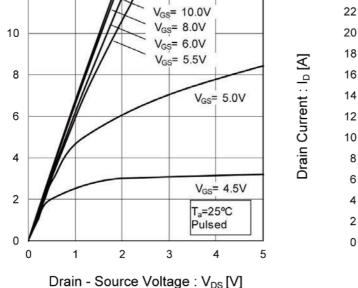
• Electrical characteristic curves



Fig.4 Typical Output Characteristics(I)

Fig.5 Typical Output Characteristics(II)

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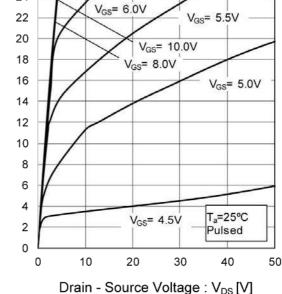


Fig.6 Tj = 150°C Typical Output Characteristics (I)



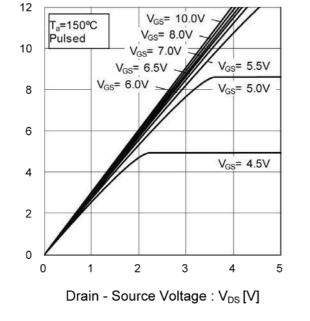
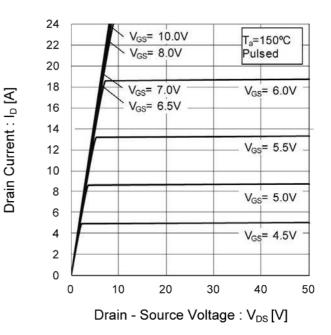


Fig.7 Tj = 150°C Typical Output Characteristics (II)





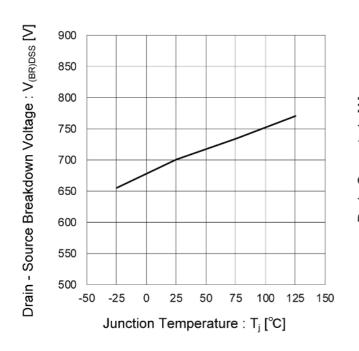


Fig.8 Breakdown Voltage vs. Junction Temperature

Fig.9 Typical Transfer Characteristics

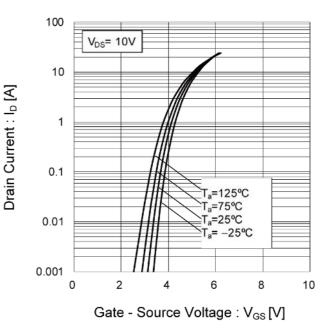


Fig.10 Gate Threshold Voltage vs. Junction Temperature

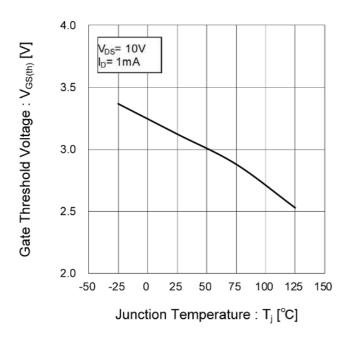


Fig.11 Forward Transfer Admittance vs. Drain Current

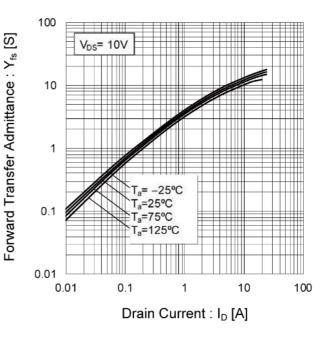




Fig.13 Static Drain - Source On - State

Resistance vs. Junction Temperature

•Electrical characteristic curves

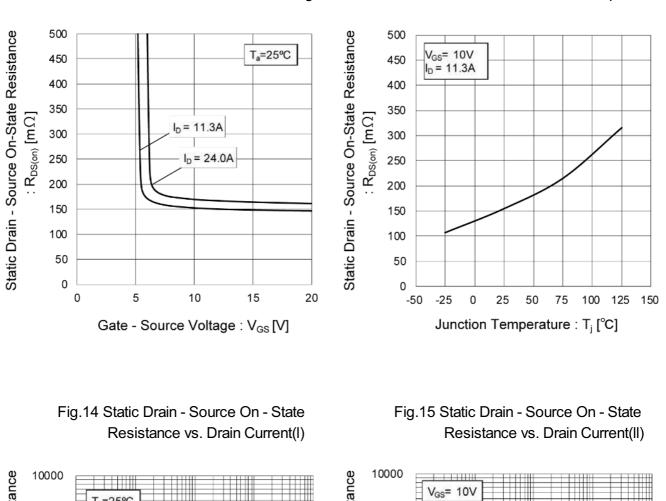
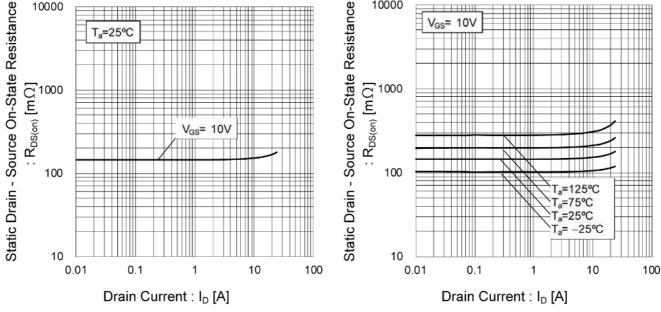


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage





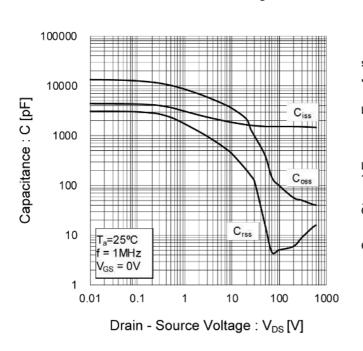
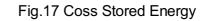


Fig.16 Typical Capacitance vs.

Drain - Source Voltage



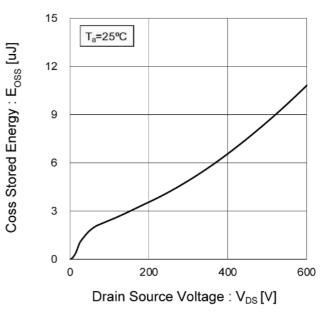
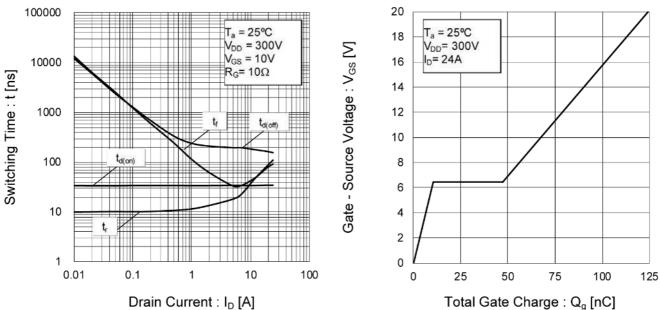


Fig.18 Switching Characteristics

Fig.19 Dynamic Input Characteristics



Total Gate Charge : Qg [nC]



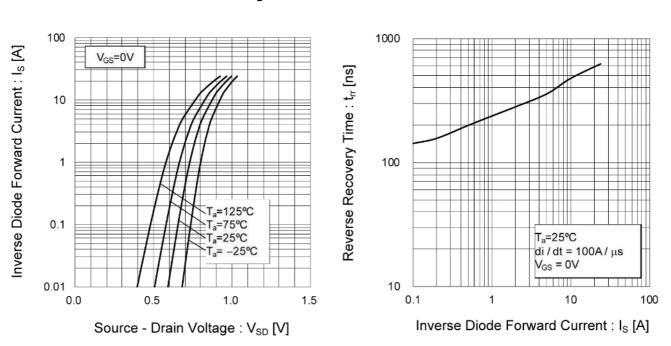


Fig.20 Inverse Diode Forward Current vs. Source - Drain Voltage

Fig.21 Reverse Recovery Time vs. Inverse Diode Forward Current



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

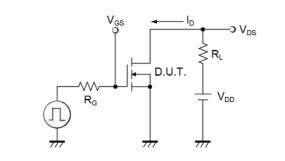


Fig.2-1 Gate Charge Measurement Circuit

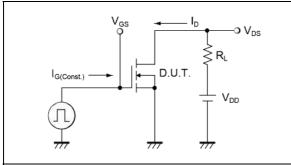


Fig.3-1 Avalanche Measurement Circuit

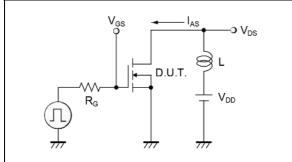


Fig.4-1 dv/dt Measurement Circuit

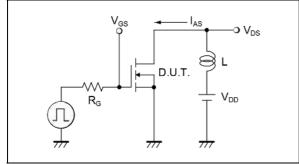


Fig.5-1 dv/dt Measurement Circuit

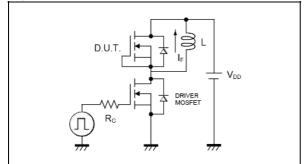


Fig.1-2 Switching Waveforms

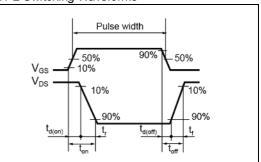


Fig.2-2 Gate Charge Waveform

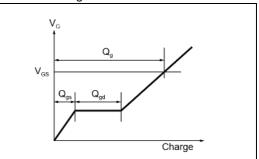


Fig.3-2 Avalanche Waveform

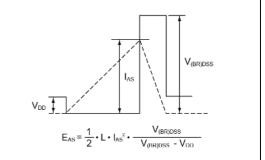


Fig.4-2 dv/dt Waveform

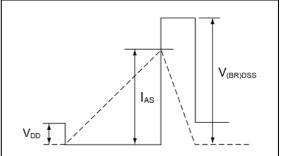
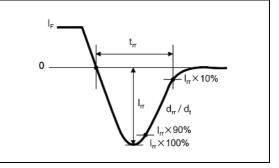
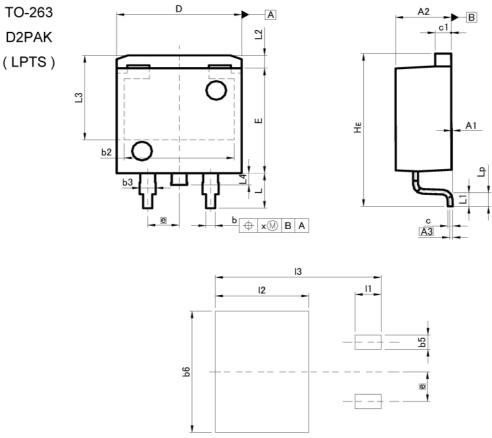


Fig.5-2 dv/dt Waveform





Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INCHES		
DIM -	MIN	MAX	MIN	MAX	
A1	0.00	0.30	0.000	0.012	
A2	4.30	4.70	0.169	0.185	
A3	0	25	0.0	10	
b	0.68	0.98	0.027	0.039	
b2	8.90			350	
b3	1.14	1.44	0.045	0.057	
C	0.30	0.60	0.012	0.024	
c1	1.10	1.50	0.043	0.059	
D	9.80	10.40	0.386	0.409	
E	8.80	9.20	0.346	0.362	
e	2.	54	0.100		
HE	12.80	13.40	0.504	0.528	
L	2.70	3.30	0.106	0.130	
L1	1.	20	0.047		
L2	1.	10	0.043		
L3	7.:	25	0.285		
L4	1.0	00	0.039		
Lp	0.90	1.50	0.035	0.059	
x	.	0.25	1	0.010	
	MILIM	ETERS	INC	HES	
DIM -	MIN	MAX	MIN	MAX	
b5	H (1.23		0.049	
b6	(m)	10.40		0.409	
n	<u>199</u> 3)	2.10	18 <u>2</u> 6	0.083	
12	350 Å	7.55	1000	0.297	
13	H3	13.40	() ()	0.528	

Dimension in mm/inches





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 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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